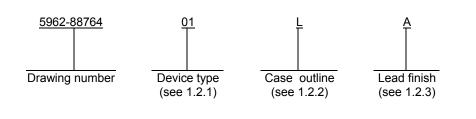
						I	REVISI	ONS										
LTR		DESCRIPTION						DATE (YR-MO-DA)			APPROVED							
А	Add case outline 3 II, and figures 1 ar	Add case outline 3. Add vendor CAGE 1ES66. Made changes to tables I a II, and figures 1 and 2							and	91-09-17			M. A. FRYE					
В	Update drawing to	current	require	ements	s. Edito	orial ch	anges t	hrough	out c	lrw	04-07-08			R. MONNIN				
С	Make correction to	the Moo	de 1 tir	ming w	aveforr	n as sp	pecified	under	figure	3		06-0)1-18			R. M	ONNIN	
THE ORIGINAI	L FIRST SHEET OF	THIS DR	AWIN	G HAS	BEEN	REPL	ACED.											
	IL FIRST SHEET OF	THIS DR	AWIN	G HAS	BEEN	REPL	ACED.					1	1	1	1	1	1	1
REV	L FIRST SHEET OF	THIS DR.	AWIN	G HAS	BEEN	REPL	ACED.											
REV SHEET			AWIN	G HAS	BEEN	REPL	ACED.											
REV SHEET REV	L FIRST SHEET OF		AWIN	G HAS	BEEN	REPL	ACED.											
REV SHEET REV SHEET			AWIN	G HAS							C		C					
REV SHEET REV SHEET REV STATUS		REV		G HAS	BEEN	REPL C 2	ACED.		C 5	C 6	C 7	C 8	C	C 10	C 11	C 12		
REV SHEET REV SHEET		REV SHEE	T) BY	C	C	C	C	5	6	7	8	9	_	11	12	US	
REV SHEET REV SHEET REV STATUS OF SHEETS PMIC N/A		REV SHEE GAF	ET PARED RY ZAK) BY HN	C 1	C	C	C	5	6 EFEN	7 SE SI	8 UPPL	9 Y CE , OHI0	10	11 R COL 218-39	12 UMB	US	
REV SHEET REV SHEET REV STATUS OF SHEETS PMIC N/A STA MICRO DR/ THIS DRAWII FOR U DEPA AND AGEI	NDARD OCIRCUIT AWING ING IS AVAILABLE JSE BY ALL ARTMENTS INCIES OF THE	REV SHEE PREP GAF CHEC CHA	ET PARED RY ZAI RED F RLES) BY HN E. BES) BY (. HEC	C 1	C 2	C	C 4 MIC CO	5 DI	6 EFEN CC	7 SE SI DLUM http	8 UPPL IBUS p://ww	9 Y CE , OHIO /w.ds	10 NTER O 432	11 218-39 a.mil	12 -UMB 990 -BIT /	4/D	
REV SHEET REV SHEET REV STATUS OF SHEETS PMIC N/A STA MICRO DR/ THIS DRAWII FOR U DEPA AND AGEI DEPARTMEN	NDARD OCIRCUIT AWING IS AVAILABLE JSE BY ALL ARTMENTS INCIES OF THE INCIES OF THE INCIES OF THE INCIES OF THE	REV SHEE PREP GAF CHEC CHA	ET PARED RY ZAI RED F RLES) BY HN E. BES) BY (. HEC	C 1 SORE	C 2	C	C 4 MIC CO	5 DI CROC	6 EFEN CC	7 SE SI DLUM http	8 UPPL IBUS p://ww	9 Y CE , OHIO /w.ds	10 NTER 0 432 cc.dl	11 218-39 a.mil	12 -UMB 990 -BIT /	4/D	
REV SHEET REV SHEET REV STATUS OF SHEETS PMIC N/A STA MICRO DR/ THIS DRAWII FOR U DEPA AND AGEI DEPARTMEN	NDARD OCIRCUIT AWING ING IS AVAILABLE JSE BY ALL ARTMENTS INCIES OF THE	REV SHEE PREP GAF CHEC CHA APPR WILL DRAW	ET PARED RY ZAH CKED E RLES COVED LIAM K) BY HN E. BES) BY (. HEC APPR(89-0	C 1 SORE KMAN	C 2	C	C 4 MIC CO SIL	5 DI CROC	6 EFEN CC CIRCI RTEF	7 SE SI DLUM http	8 IBUS DIGIT IGH	9 Y CE , OHIO /w.ds	10 NTER D 432 cc.dl	11 218-33 a.mil	12 -UMB 990 -BIT /	A/D IIC	

1.	SCOPE

1.1 <u>Scope</u>. This drawing describes device requirements for MIL-STD-883 compliant, non-JAN class level B microcircuits in accordance with MIL-PRF-38535, appendix A.

1.2 Part or Identifying Number (PIN). The complete PIN is as shown in the following example:



1.2.1 <u>Device type(s)</u>. The device type(s) identify the circuit function as follows:

Generic number	Circuit function	Total unadjusted error
7824T	4-channel 8-bit A/D converter	±1.0 LSB
7824U	4-channel 8-bit A/D converter	±0.5 LSB
7828T	8-channel 8-bit A/D converter	±1.0 LSB
7828U	8-channel 8-bit A/D converter	±0.5 LSB
	7824T 7824U 7828T	7824T4-channel 8-bit A/D converter7824U4-channel 8-bit A/D converter7828T8-channel 8-bit A/D converter

1.2.2 <u>Case outline(s)</u>. The case outline(s) are as designated in MIL-STD-1835 and as follows:

Outline letter	Descriptive designator	<u>Terminals</u>	Package style
3	CQCC1-N28	28	Square leadless chip carrier
L	GDIP3-T24 or CDIP4-T24	24	Dual-in-line
Х	GDIP1-T28 or CDIP2-T28	28	Dual-in-line

1.2.3 Lead finish. The lead finish is as specified in MIL-PRF-38535, appendix A.

1.3 Absolute maximum ratings.

V _{DD} to ground range	0 V dc to +7 V dc
Digital input voltage to ground ($\overline{\text{RD}}$, $\overline{\text{CS}}$, A0, A1 and A2)	-0.3 V dc to $V_{\mbox{DD}}$
Digital output voltage to ground (DB0, DB7, RDY and INT) $V_{REF}(+)$ to ground $V_{REF}(-)$ to ground Analog input, any channel Storage temperature range Lead temperature (soldering, 10 seconds) Power dissipation (P _D) Thermal resistance, junction-to-case (θ_{JC}) Thermal resistance, junction-to-ambient (θ_{JA}) (all cases)	-0.3 V dc to V _{DD} V _{REF} (-) to V _{DD} 0 V dc to V _{REF} (+) -0.3 V dc to V _{DD} -65°C to +150°C +300°C 450 mW <u>1</u> / See MIL-STD-1835
Junction temperature (T _J)	+175°C

<u>1</u>/ Derate above $T_A = +75^{\circ}C$ at 6.0 mW/°C for case outlines L, X, and 3.

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1.4 Recommended operating conditions.

Supply voltage range (V _{DD})	+4.75 V dc to +5.25 V dc
Positive reference voltage V _{REF} (+)	+5.0 V dc
Negative reference voltage V _{REF} (-)	0 V dc
Ground potential (GND)	0 V dc
Ambient operating temperature range (T _A)	-55°C to +125°C

2. APPLICABLE DOCUMENTS

2.1 <u>Government specification, standards, and handbooks</u>. The following specification, standards, and handbooks form a part of this drawing to the extent specified herein. Unless otherwise specified, the issues of these documents are those cited in the solicitation or contract.

DEPARTMENT OF DEFENSE SPECIFICATION

MIL-PRF-38535 - Integrated Circuits, Manufacturing, General Specification for.

DEPARTMENT OF DEFENSE STANDARDS

MIL-STD-883 -	-	Test Method Standard Microcircuits.
MIL-STD-1835 -	-	Interface Standard Electronic Component Case Outlines.

DEPARTMENT OF DEFENSE HANDBOOKS

MIL-HDBK-103 - List of Standard Microcircuit Drawings. MIL-HDBK-780 - Standard Microcircuit Drawings.

(Copies of these documents are available online at http://assist.daps.dla.mil/quicksearch/ or http://assist.daps.dla.mil or from the Standardization Document Order Desk, 700 Robbins Avenue, Building 4D, Philadelphia, PA 19111-5094.)

2.2 <u>Order of precedence</u>. In the event of a conflict between the text of this drawing and the references cited herein, the text of this drawing takes precedence. Nothing in this document, however, supersedes applicable laws and regulations unless a specific exemption has been obtained.

3. REQUIREMENTS

3.1 <u>Item requirements</u>. The individual item requirements shall be in accordance with MIL-PRF-38535, appendix A for non-JAN class level B devices and as specified herein. Product built to this drawing that is produced by a Qualified Manufacturer Listing (QML) certified and qualified manufacturer or a manufacturer who has been granted transitional certification to MIL-PRF-38535 may be processed as QML product in accordance with the manufacturers approved program plan and qualifying activity approval in accordance with MIL-PRF-38535. This QML flow as documented in the Quality Management (QM) plan may make modifications to the requirements herein. These modifications shall not affect form, fit, or function of the device. These modifications shall not affect the PIN as described herein. A "Q" or "QML" certification mark in accordance with MIL-PRF-38535 is required to identify when the QML flow option is used.

3.2 <u>Design, construction, and physical dimensions</u>. The design, construction, and physical dimensions shall be as specified in MIL-PRF-38535, appendix A and herein.

3.2.1 <u>Case outlines</u>. The case outlines shall be in accordance with 1.2.2 herein.

3.2.2 <u>Terminal connections</u>. The terminal connections shall be as specified on figure 1.

3.2.3 <u>Truth table</u>. The truth table shall be as specified on figure 2.

3.3 <u>Electrical performance characteristics</u>. Unless otherwise specified herein, the electrical performance characteristics are as specified in table I and shall apply over the full ambient operating temperature range.

3.4 <u>Electrical test requirements</u>. The electrical test requirements shall be the subgroups specified in table II. The electrical tests for each subgroup are described in table I.

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TABLE I. Electrical performance characteristics.									
Test	Symbol	$-55^{\circ}C \le T_A \le +12$	$\begin{array}{c c} Conditions & \underline{1}/, \underline{2}/ \\ -55^{\circ}C \leq T_A \leq +125^{\circ}C & Group \\ nless otherwise specified & subgroup \end{array}$				Lin	nits	Unit
Resolution	RES	Guaranteed minimur resolution for which		1, 2,	3	All	Min 8.0	Max	Bits
Total unadjusted error <u>3</u> /	TUE	codes are missing		1, 2,	3	01, 03		±1.0	LSB
· -				1		02, 04		±1.0	
				2, 3,	12			±0.5	
Analog input leakage current	I _{IN}	Any channel		1, 2,	3	All		±3.0	μA
Reference input <u>4</u> / resistance	R _{IN}			1, 2,	3	All	1.0	4.0	kΩ
Digital input high voltage	VIH	RD, CS, A0, A1, A	2 <u>5</u> /	1, 2,	3	All	2.4		V
Digital input low voltage	VIL	RD, CS, A0, A1, A	2 <u>5</u> /	1, 2,	3	All		0.8	V
Digital input high current	Ιн	RD, CS, A0, A1, A	2 <u>5</u> /	1, 2,	3	All		1.0	μA
Digital input low current	١ _{١L}	RD, CS, A0, A1, A	2 <u>5</u> /	1, 2,	3	All		-1.0	μA
Digital output high voltage	V _{OH}	DB ₀ – DB ₇ , INT , I _{SOURCE} = 360 μΑ		1, 2,	3	All	4.0		V
Digital output low voltage	V _{OL}	DB ₀ – DB ₇ , INT , I _{SINK} = 1.6 mA		1, 2,	3	All		0.4	V
		RDY, I _{SINK} = 2.6 m/	A <u>6</u> ∕					0.4	
Floating state leakage current	IOUT	DB ₀ – DB ₇ only		1, 2,	3	All		3.0	μA
Supply current from V_{DD}	I _{DD}	CS = RD = 2.4 V		1, 2,	3	All		20	mA
Power supply sensitivity	PSS	V _{DD} = +5.0 V ±5.0%)	1, 2,	3	All		±0.25	LSB
Analog input capacitance <u>4</u> /	C _{IN1}	0 V to 5.0 V, T _A = +2	25°C	4		All		45	pF
Digital input capacitance <u>4</u> /	C _{IN2}	 RD , CS , A0, A1, A T _A = +25°C	2 <u>5</u> /	4		All		8.0	pF
Digital output <u>4</u> / capacitance	COUT	T _A = +25°C		4		All		8.0	pF
Slew rate, tracking <u>4</u> /	SR	T _A = +25°C		4		All		0.157	V/µs
Functional tests		See 4.3.1d and figur	e 2	7, 8	3	All			
See footnotes at end of table.									
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Test	Symbol	$\begin{array}{l} Conditions \underline{1}, \underline{2}/\\ -55^{\circ}C \leq T_A \leq +125^{\circ}C\\ unless \ otherwise \ specified \end{array}$	Group A subgroups	Device type	Limits		Unit
					Min	Max	
CS to RD setup time	tcss	See figure 3	9, 10, 11	All	0		ns
CS to RD hold time	tCSH	See figure 3	9, 10, 11	All	0		ns
CS to RDY delay	t _{RDY}	C _L = 50 pF,	9	All		40	ns
		pull-up resistor = 5.0 k Ω , see figure 3	10, 11			60	
Conversion time, mode 0	tCRD	See figure 3	9	All		2.0	μs
			10, 11			2.8	
Data access time after \overline{RD} ,	tACC1	See figure 3 <u>7</u> / <u>8</u> /	9	All		85	ns
mode 1			10, 11			120	
RD to INT delay	tinth	C _L = 50 pF	9	All		75	ns
			10, 11			100	
Data hold time	tDH	See figure 3 and 4 <u>9</u> /	9	All		60	ns
			10, 11			70	
Delay time between conversions	tP	See figure 3	9	All	500		ns
			10, 11		600		
Read pulse width, mode 1	t _{RD}	See figure 3	9	All	60	600	ns
			10, 11		80	400	
Data access time after INT	tACC2	See figure 3 <u>7</u> / <u>8</u> /	9	All		50	ns
			10, 11			70	

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TABLE I. Electrical performance characteristics - continued.

Test	Symbol	$\begin{array}{ll} Conditions & \underline{1}/, \underline{2}/ \\ -55^\circ C \leq T_A \leq +125^\circ C \\ unless \ otherwise \ specified \end{array}$	Group A subgroups	Device type	Lin	nits	Unit
					Min	Max	
Multiplexer address setup time	t _{AS}	See figure 3	9, 10, 11	All	0		ns
Multiplexer address hold time	t _{AH}	See figure 3	9	All	30		ns
			10, 11		40		

- $1/V_{DD}$ = +5.0 V, V_{REF}(+) = +5.0 V, and V_{REF}(-) = GND = 0 V unless otherwise specified. Specifications apply for mode 0. All input control signals are specified with t_r = t_f = 20 ns (10% to 90% of +5.0 V) and timed from a voltage level of 1.6 V.
- 2/ Subgroups 10 and 11, if not tested, shall be guaranteed to the limits specified in table I.
- 3/ Total unadjusted error includes offset, full scale, and linearity errors.
- <u>4</u>/ The (C_{IN1}, C_{IN2}, R_{IN}, C_{OUT}, and SR measurements) are measured initially and after any process or design changes which may affect these tests.
- 5/ A2 applies to device types 03 and 04 only.
- 6/ RDY is an open drain output.
- 7/ Measured with load circuits of figure 5 and defined as the time required for an output to cross 0.8 V or 2.4 V.
- 8/ If not tested, shall be guaranteed to the limits specified in table I herein.
- <u>9</u>/ Defined as the time required for the data lines to change 0.5 V when loaded with the circuits of figure 4 and is measured only for the initial test and after process or design changes which may affect t_{DH}.

3.5 <u>Marking</u>. Marking shall be in accordance with MIL-PRF-38535, appendix A. The part shall be marked with the PIN listed in 1.2 herein. In addition, the manufacturer's PIN may also be marked. For packages where marking of the entire SMD PIN number is not feasible due to space limitations, the manufacturer has the option of not marking the "5962-" on the device.

3.5.1 <u>Certification/compliance mark</u>. A compliance indicator "C" shall be marked on all non-JAN devices built in compliance to MIL-PRF-38535, appendix A. The compliance indicator "C" shall be replaced with a "Q" or "QML" certification mark in accordance with MIL-PRF-38535 to identify when the QML flow option is used.

3.6 <u>Certificate of compliance</u>. A certificate of compliance shall be required from a manufacturer in order to be listed as an approved source of supply in MIL-HDBK-103 (see 6.6 herein). The certificate of compliance submitted to DSCC-VA prior to listing as an approved source of supply shall affirm that the manufacturer's product meets the requirements of MIL-PRF-38535, appendix A and the requirements herein.

3.7 <u>Certificate of conformance</u>. A certificate of conformance as required in MIL-PRF-38535, appendix A shall be provided with each lot of microcircuits delivered to this drawing.

3.8 Notification of change. Notification of change to DSCC-VA shall be required for any change that affects this drawing.

3.9 <u>Verification and review</u>. DSCC, DSCC's agent, and the acquiring activity retain the option to review the manufacturer's facility and applicable required documentation. Offshore documentation shall be made available onshore at the option of the reviewer.

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Device types	01 and 02	03 and 04
Case outlines	L	X and 3
Terminal number	Terminal symbol	
1	AIN 4	AIN 6
2	AIN 3	AIN 5
3	AIN 2	AIN 4
4	AIN 1	AIN 3
5	NC	AIN 2
6	DB0	AIN 1
7	DB1	NC
8	DB2	DB0
9	DB3	DB1
10	RD	DB2
11	INT	DB3
12	GND	RD
13	V _{REF} (-)	INT
14	V _{REF} (+)	GND
15	RDY	V _{REF} (-)
16	CS	V _{REF} (+)
17	DB4	RDY
18	DB5	CS
19	DB6	DB4
20	DB7	DB5
21	A1	DB6
22	A0	DB7
23	NC	A2
24	V _{DD}	A1
25		A0
26		V _{DD}
27		AIN 8
28		AIN 7

NC = No connection

FIGURE 1. Terminal connections.

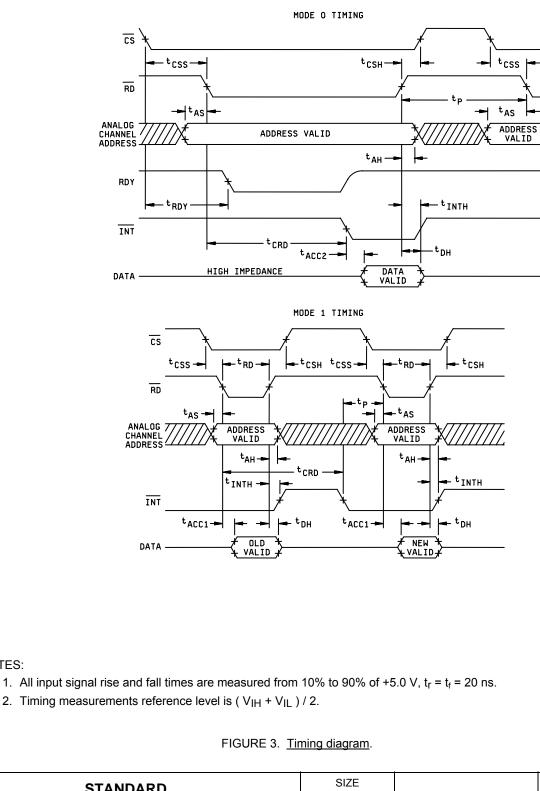
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Device types	s 01 and 02	Device types 03 and 04			Channel
A1	A0	A2	A1	A0	Channer
0	0	0	0	0	AIN 1
0	1	0	0	1	AIN 2
1	0	0	1	0	AIN 3
1	1	0	1	1	AIN 4
		1	0	0	AIN 5
		1	0	1	AIN 6
		1	1	0	AIN 7
		1	1	1	AIN 8

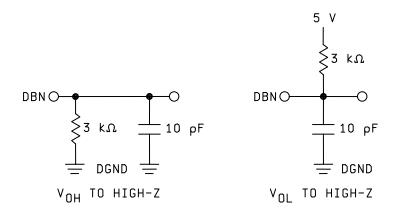
0 = Logic low state 1 = Logic high state

FIGURE 2. Truth table.

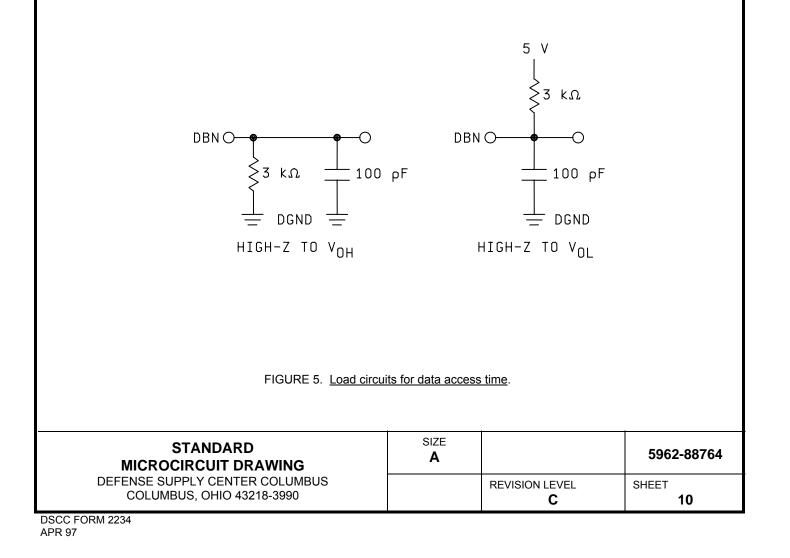
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NOTES:







4. VERIFICATION

4.1 <u>Sampling and inspection</u>. Sampling and inspection procedures shall be in accordance with MIL-PRF-38535, appendix A.

4.2 <u>Screening</u>. Screening shall be in accordance with method 5004 of MIL-STD-883, and shall be conducted on all devices prior to quality conformance inspection. The following additional criteria shall apply:

- a. Burn-in test, method 1015 of MIL-STD-883.
 - (1) Test condition A, B, C, or D. The test circuit shall be maintained by the manufacturer under document revision level control and shall be made available to the preparing or acquiring activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in method 1015 of MIL-STD-883.
 - (2) $T_A = +125^{\circ}C$, minimum.
- b. Interim and final electrical test parameters shall be as specified in table II herein, except interim electrical parameter tests prior to burn-in are optional at the discretion of the manufacturer.

4.3 <u>Quality conformance inspection</u>. Quality conformance inspection shall be in accordance with method 5005 of MIL-STD-883 including groups A, B, C, and D inspections. The following additional criteria shall apply.

4.3.1 Group A inspection.

- a. Tests shall be as specified in table II herein.
- b. Subgroups 5 and 6 in table I, method 5005 of MIL-STD-883 shall be omitted.
- c. Subgroup 4 (C_{IN1}, C_{IN2}, R_{IN}, C_{OUT}, and SR measurement) shall be measured only for the initial test and after process or design changes which may affect input capacitance.
- d. Subgroups 7 and 8 shall include verification of the truth table.
- e. Subgroup 12 test is used for grading and part selection at T_A = 25°C, and is not included in PDA calculations.

4.3.2 Groups C and D inspections.

- a. End-point electrical parameters shall be as specified in table II herein.
- b. Steady-state life test conditions, method 1005 of MIL-STD-883.
 - (1) Test condition A, B, C, or D. The test circuit shall be maintained by the manufacturer under document revision level control and shall be made available to the preparing or acquiring activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in method 1005 of MIL-STD-883.
 - (2) $T_A = +125^{\circ}C$, minimum.
 - (3) Test duration: 1,000 hours, except as permitted by method 1005 of MIL-STD-883.

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MIL-STD-883 test requirements	Subgroups
	(in accordance with
	MIL-STD-883, method 5005,
	table I)
Interim electrical parameters	
(method 5004)	
Final electrical test parameters	4* 0 0 7 40
(method 5004)	1*, 2, 3, 7, 12
Group A test requirements	1, 2, 3, 4**, 7, 8, 9, 10***,
(method 5005)	11***, 12****
Groups C and D end-point	
electrical parameters	1
(method 5005)	
	•

TABLE II. Electrical test requirements.

* PDA applies to subgroup 1.

** See 4.3.1c.

*** Subgroups 10 and 11, if not tested, shall be guaranteed to the limits specified in table I herein.

**** See 4.3.1e.

5. PACKAGING

5.1 <u>Packaging requirements</u>. The requirements for packaging shall be in accordance with MIL-PRF-38535, appendix A.

6. NOTES

6.1 <u>Intended use</u>. Microcircuits conforming to this drawing are intended for use for Government microcircuit applications (original equipment), design applications, and logistics purposes.

6.2 <u>Replaceability</u>. Microcircuits covered by this drawing will replace the same generic device covered by a contractorprepared specification or drawing.

6.3 <u>Configuration control of SMD's</u>. All proposed changes to existing SMD's will be coordinated with the users of record for the individual documents. This coordination will be accomplished using DD Form 1692, Engineering Change Proposal.

6.4 <u>Record of users</u>. Military and industrial users shall inform Defense Supply Center Columbus (DSCC) when a system application requires configuration control and the applicable SMD. DSCC will maintain a record of users and this list will be used for coordination and distribution of changes to the drawings. Users of drawings covering microelectronics devices (FSC 5962) should contact DSCC-VA, telephone (614) 692-0544.

6.5 <u>Comments</u>. Comments on this drawing should be directed to DSCC-VA, Columbus, Ohio 43218-3990, or telephone (614) 692-0547.

6.6 <u>Approved sources of supply</u>. Approved sources of supply are listed in MIL-HDBK-103. The vendors listed in MIL-HDBK-103 have agreed to this drawing and a certificate of compliance (see 3.6 herein) has been submitted to and accepted by DSCC-VA.

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STANDARD MICROCIRCUIT DRAWING BULLETIN

DATE: 06-01-18

Approved sources of supply for SMD 5962-88764 are listed below for immediate acquisition information only and shall be added to MIL-HDBK-103 and QML-38535 during the next revision. MIL-HDBK-103 and QML-38535 will be revised to include the addition or deletion of sources. The vendors listed below have agreed to this drawing and a certificate of compliance has been submitted to and accepted by DSCC-VA. This information bulletin is superseded by the next dated revision of MIL-HDBK-103 and QML-38535. DSCC maintains an online database of all current sources of supply at http://www.dscc.dla.mil/Programs/Smcr/.

Standard microcircuit drawing PIN <u>1</u> /	Vendor CAGE number	Vendor similar PIN <u>2</u> /
5962-8876401LA	1ES66	MX7824TQ/883B
	24355	AD7824TQ/883B
5962-8876402LA	1ES66	MX7824UQ/883B
	24355	AD7824UQ/883B
5962-8876403XA	1ES66	MX7828TQ/883B
	24355	AD7828TQ/883B
5962-8876404XA	1ES66	MX7828UQ/883B
	24355	AD7828UQ/883B
5962-88764043A	24355	AD7828UE/883B

- 1/ The lead finish shown for each PIN representing a hermetic package is the most readily available from the manufacturer listed for that part. If the desired lead finish is not listed contact the vendor to determine its availability.
- 2/ <u>Caution</u>. Do not use this number for item acquisition. Items acquired to this number may not satisfy the performance requirements of this drawing.

 Vendor CAGE
 Vendor name

 number
 and address

 1ES66
 Maxim Integrated Products

 120 San Gabriel Dr.
 Sunnyvale, CA 94086-5125

 24355
 Analog Devices

 Route 1 Industrial Park
 P.O. Barry 0409

P.O. Box 9106 Norwood, MA 02062 Point of contact: Raheen Business Park Limerick, Ireland

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